



ABSTRACT

Pulsed-field magnetization of a high-temperature Bi-2221 superconductor with various pinning landscapes has been studied by means of the Monte Carlo method. Computations have been performed for broad ranges of pulse parameters, such as amplitude and shape, and sample parameters, such as temperature and the concentration and type of distribution of defects (pinning centers). The time-dependences and distribution profiles of the average trapped $U_{\text{in-plane}}$ magnetic field have been computed for various conditions. The differences between field-trapping efficiencies of different pinning landscapes have been demonstrated for various temperatures.



(on the left) The time-dependences of the averaged magnetic field induction B_a inside three samples with different pinning landscapes: a triangular lattice (T), a conformal triangular array (CT), and a random distribution (R); A samples contain approximately the same number of defects (608) corresponding to a density of $4 \cdot 10^9$ cm⁻²; (on the right) The distribution profiles of the trapped magnetic field B_{t} (after the external field has been switched) off) for samples with different numbers of defects (provided in the legend above) distributed in 3 different ways (T, CT and R as denoted on the left of the images); Here, $H_0 = 2100$ Oe.

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Monte Carlo simulations of vortex dynamics in high-temperature superconductors under pulsed-field magnetization

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$$B_a = N\Phi_0 / (L_x L_y)$$

$$\mathbf{h}_{\text{vort}}(r) = \frac{\Phi_0}{2\pi\lambda^2} \times \begin{cases} \log(\kappa) - 0.28, \ r \le \xi \\ \mathbf{K}_0(r/\lambda), \qquad r > \xi \end{cases}$$

 $\mathcal{E} = U_0$ $U_{
m magn}$ (2) $U_{\mathrm{bdr}}(|\mathbf{r}_i|)$ $U_{\text{pin}} \left(\left| \mathbf{r}_{i} \right| \right)$ <u>(on the</u> dependences with different (T (top row), ((bottom different (trapezoidal and exponen on the left and different pulse samples conta (below) The of the trapped with different at various tem

 $G = \delta$



COMPUTATIONAL MODEL



he CT array requires much higher pulse itudes for full magnetization but allows for trapped flux at lesser defect densities; The increasing temperature causes moactivated flux creep which leads to magnetization upon repetitive essive cation of pulses but also to step-like flux ation from CT arrays.